

|    | L # | Hits  | Search Text   | DBs  | Time Stamp          |
|----|-----|-------|---|--|---------------------|
| 1  | L1  | 17020 | (trench groove grooved) near3<br>(oxide dioxide isolation)                                      | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>13:20 |
| 2  | L8  | 1231  | 1 and resistor  | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>13:20 |
| 3  | L15 | 225   | 1 same resistor   | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>13:20 |
| 4  | L22 | 98    | 1 with resistor   | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:01 |
| 5  | L29 | 29303 | (resistive resistivity resistor) near20<br>(isolation STI FOX field LOCOS)                      | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:09 |
| 6  | L36 | 25231 | (resistive resistor) near20 (isolation<br>STI FOX field LOCOS)                                  | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:04 |
| 7  | L43 | 2951  | (resistive resistor) near20 ((si or<br>silicon) near3 (poly or<br>polycrystalline))             | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:06 |
| 8  | L50 | 3804  | (resistive resistivity resistor) near20<br>((si or silicon) near3 (poly or<br>polycrystalline)) | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:06 |
| 9  | L57 | 597   | 29 and 50   | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:09 |
| 10 | L64 | 1     | 57 and (dummy adj gate)   | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:07 |
| 11 | L71 | 92    | 57 and ((resistive resistivity resistor)<br>near20 (spac\$3))                                   | USPAT; US-PGPUB; EPO;<br>JPO; DERWENT; IBM_TDB | 2002/03/28<br>14:10 |

|   | Document ID   |
|---|---------------|
| 1 | US 6346736 B1 |
| 2 | US 6319772 B1 |
| 3 | US 6297126 B1 |
| 4 | US 6265302 B1 |
| 5 | US 6083785 A  |
| 6 | US 5759886 A  |
| 7 | US 5652176 A  |